

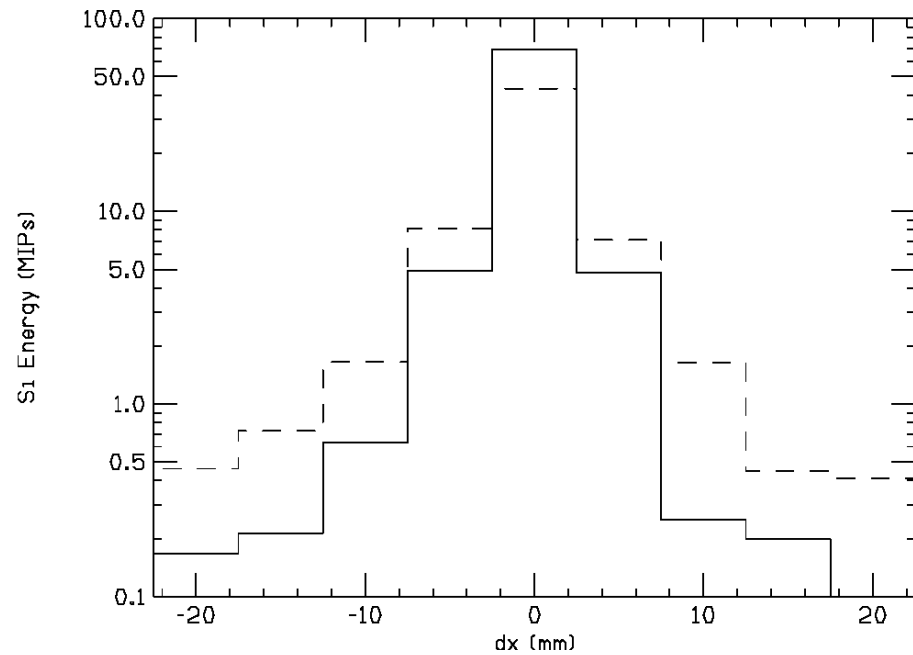
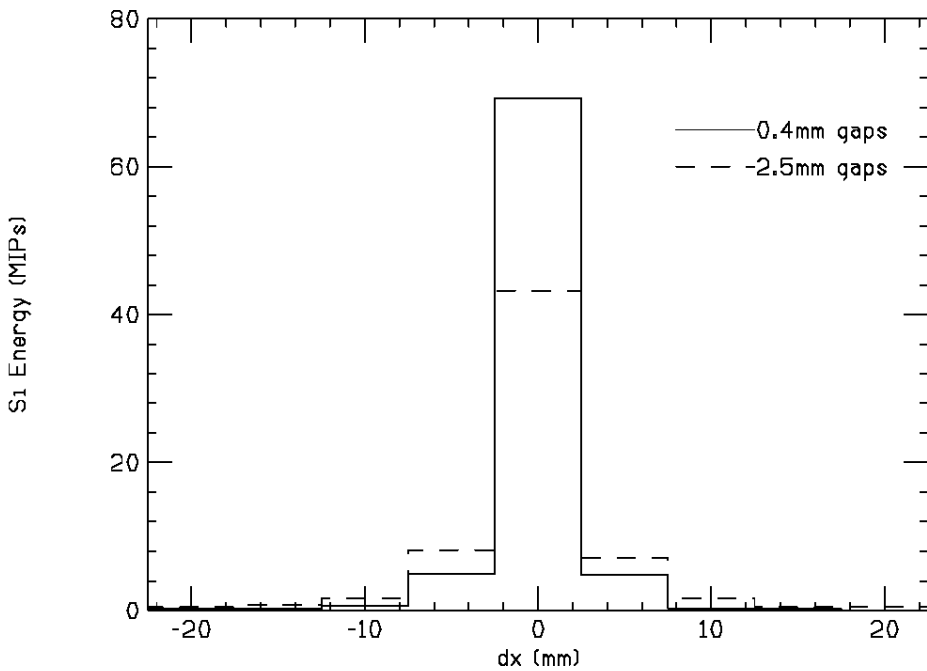
ECal Items

Ray Frey

- ECal Optimization Issues
 - Longitudinal Sampling
 - Radius
- Si/W Brief Status
- Upcoming Meetings

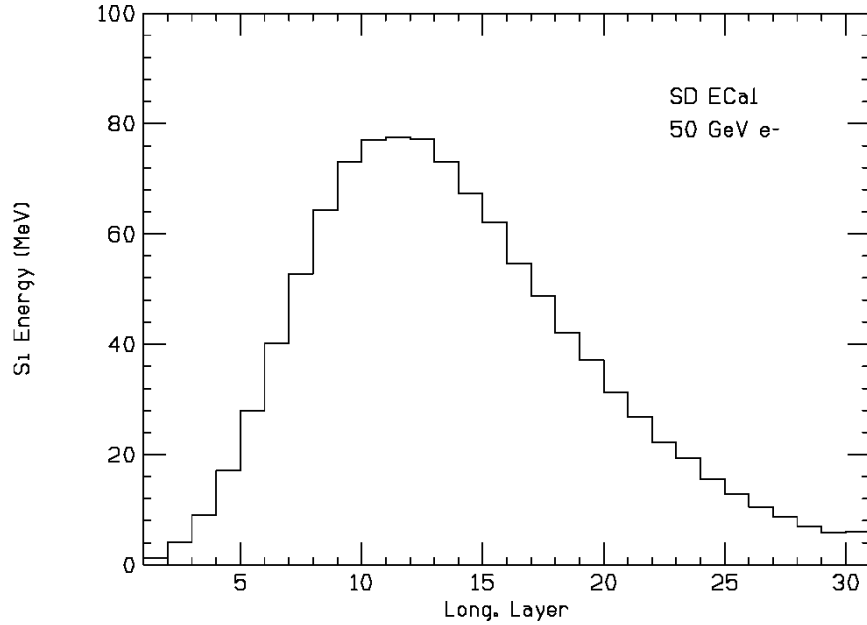
Effective Moliere radius

- Standard SD: 5×5 mm² pixels with (1) 0.4mm or (2) 2.5mm readout gaps.
- 10 GeV photons; look at layer 10



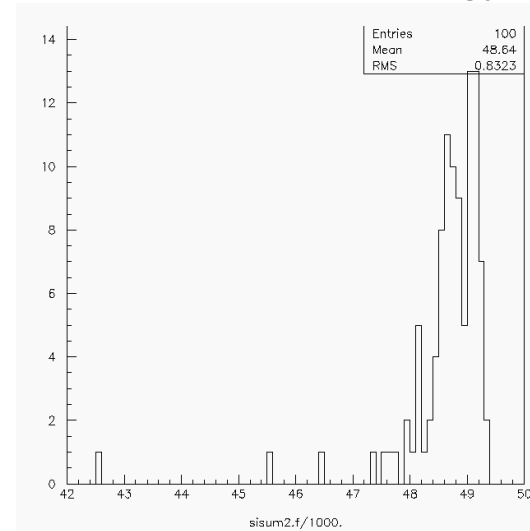
Standard SD: 30 Layers, 21 X₀.

50 GeV electrons

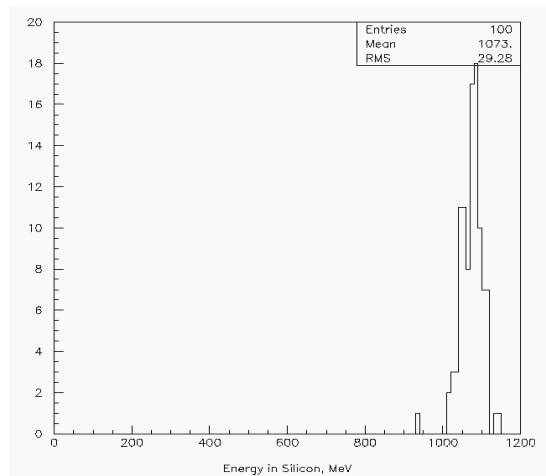


$$\sigma_E / E \approx 0.16 / \sqrt{E}$$

Total Absorbed Energy

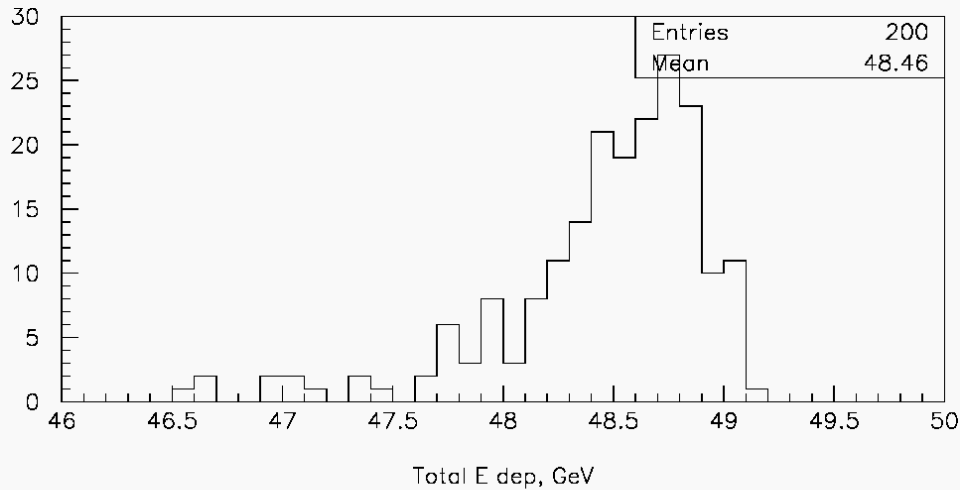


Total Energy in Si

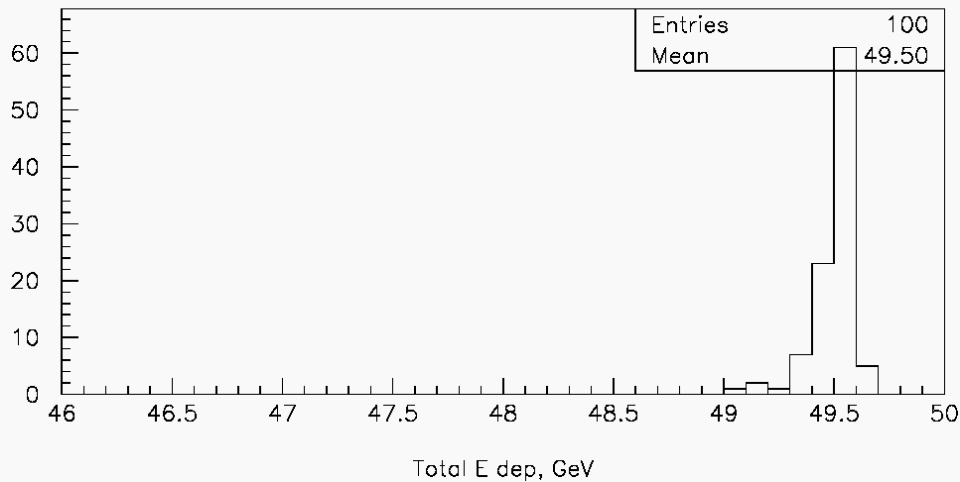


Alternative Longitudinal Sampling Configurations

50 GeV electrons



SD: $30 \times 5/7 X_0$ (21.4)

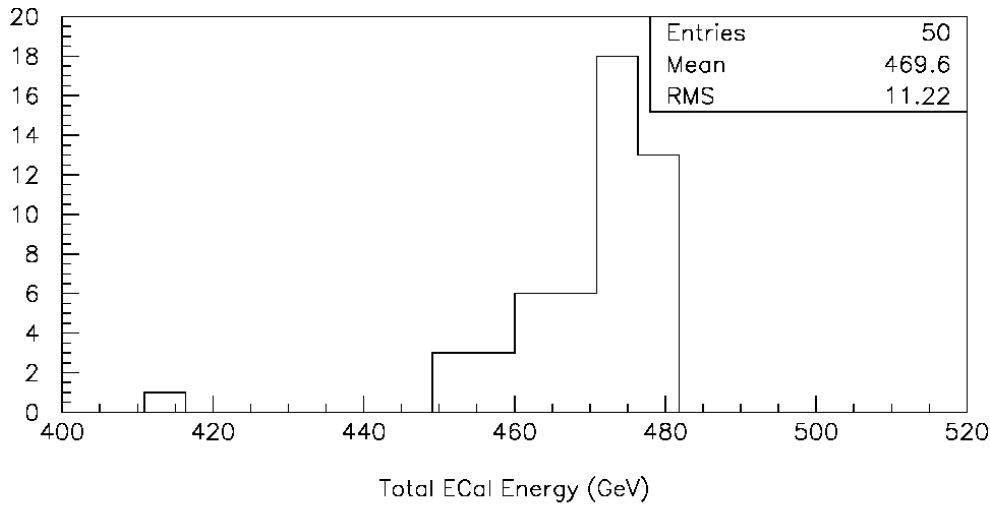


SD vB: $20 \times 5/7 X_0 + 10 \times 10/7 X_0$
(28.6)

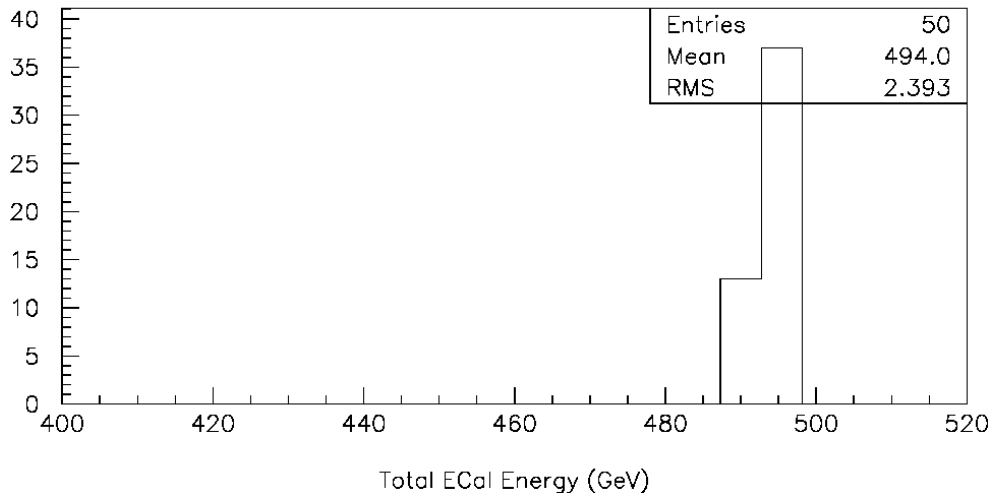
- better containment
- poorer sampling

Alternative Sampling (contd.)

500 GeV electrons



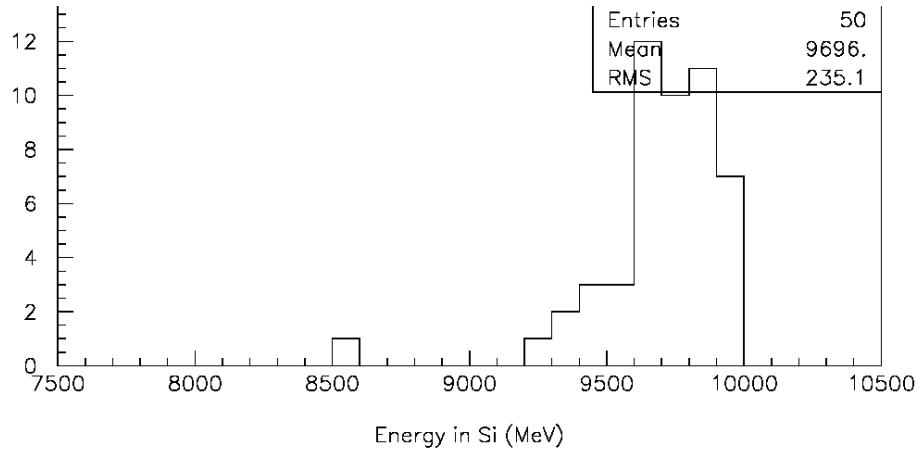
SD: $30 \times 5/7 X_0$



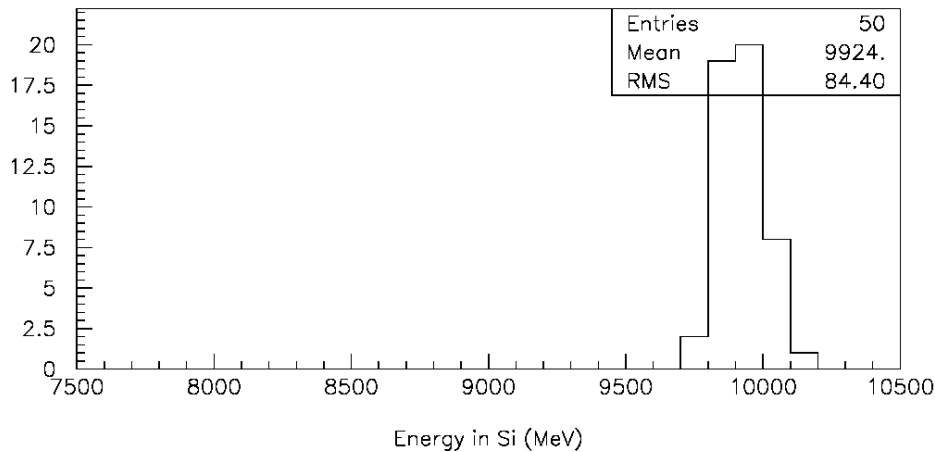
SD vB: $20 \times 5/7 X_0 + 10 \times 10/7 X_0$

Alternative Sampling (contd.) resolution

500 GeV electrons
Energy in Si



$$\text{SD: } 30 \times \frac{5}{7} X_0$$



$$\text{SD vB: } 20 \times \frac{5}{7} X_0 + 10 \times \frac{10}{7} X_0$$

ECal Optimizations

- Recall that in our design, transverse seg. Is nearly independent of cost. EM showers are *very* narrow, esp. not past shower max.
- Is there a downside to going to a deeper config., as vB ?
- MB shows that at $B=4T$, cost does not vary so strongly with ECAL radius. Better EFlow at $R_{in}=1.7m$?
- Remove ECal-HCal gap
- (Put W behind layer 30 ?)

W/Si Progress

- Si detectors
 - Have drawings (almost bid) from one of two vendors
 - At this point, need LCRD money to advance
- Readout Electronics
 - A first design of readout frontend (D. Freytag, SLAC)
 - seems to meet specs for performance
 - power seems OK
 - Layout looks OK for chip footprint
 - ASIC specifications document
- Preparing for first round of prototypes and tests
 - B field
 - Bump bonding